



Zener diode

Features

1. High reliability
2. Very sharp reverse characteristic
3. Zener voltage 2.4V to 47V
4. V_z -tolerance $\pm 5\%$



Applications

Voltage stabilization

Absolute Maximum Ratings

$T_j=25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Power dissipation	$T_{\text{amb}} \leqslant 75^\circ\text{C}$		P_V	500	mW
Z-current			I_Z	P_V/V_Z	mA
Junction temperature			T_j	200	$^\circ\text{C}$
Storage temperature range			T_{stg}	-65~+200	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j=25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	$I=9.5\text{mm}(3/8")$ $T_L=\text{constant}$	R_{thJA}	300	K/W

Stresses exceeding maximum ratings may damage the device. Maximum ratings are stress ratings only. Functional operation above the recommended operating conditions is not implied. Extended exposure to stresses above the recommended operating conditions may affect device reliability.

Electrical Characteristics

$T_j=25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F=100\text{mA}$		V_F			1.5	V

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Type ¹⁾	V _{Znom}	I _{ZT}	for V _{ZT} and		Z _{ZT}	Z _{ZK} at		I _{ZK}	I _R at	V _R	I _{ZM} ²⁾
	V	mA	V ¹⁾	Ω	Ω	mA	μA	V	mA		
1N5985B	2.4	5	2.28~2.52	100	1800	0.25	100	1.0	208		
1N5987B	3.0	5	2.85~3.15	95	2000	0.25	50	1.0	167		
1N5988B	3.3	5	3.13~3.46	95	2200	0.25	25	1.0	152		
1N5989B	3.6	5	3.42~3.78	90	2300	0.25	15	1.0	139		
1N5990B	3.9	5	3.7~4.09	90	2400	0.25	10	1.0	128		
1N5991B	4.3	5	4.08~4.51	88	2500	0.25	5	1.0	116		
1N5992B	4.7	5	4.46~4.93	70	2200	0.25	3	1.5	106		
1N5993B	5.1	5	4.84~5.35	50	2050	0.25	2	2.0	98		
1N5994B	5.6	5	5.32~5.88	25	1800	0.25	2	3.0	89		
1N5995B	6.2	5	5.89~6.51	10	1300	0.25	1	4.0	81		
1N5996B	6.8	5	6.46~7.14	8.0	750	0.25	1	5.2	74		
1N5997B	7.5	5	7.12~7.87	7.0	600	0.25	0.5	6.0	67		
1N5998B	8.2	5	7.79~8.61	7.0	600	0.25	0.5	6.5	61		
1N5999B	9.1	5	8.64~9.55	10	600	0.25	0.1	7.0	55		
1N6000B	10	5	9.5~10.5	15	600	0.25	0.1	8.0	50		
1N6001B	11	5	10.45~11.55	18	600	0.25	0.1	8.4	45		
1N6002B	12	5	11.4~12.6	22	600	0.25	0.1	9.1	42		
1N6003B	13	5	12.35~13.65	25	600	0.25	0.1	9.9	38		
1N6004B	15	5	14.25~15.75	32	600	0.25	0.1	11	33		
1N6005B	16	5	15.2~16.8	36	600	0.25	0.1	12	31		
1N6006B	18	5	17.1~18.9	42	600	0.25	0.1	14	28		
1N6007B	20	5	19~21	48	600	0.25	0.1	15	25		
1N6008B	22	5	20.9~23.1	55	600	0.25	0.1	17	23		
1N6009B	24	5	22.8~25.2	62	600	0.25	0.1	18	21		
1N6010B	27	5	25.65~28.35	70	600	0.25	0.1	21	19		
1N6011B	30	5	28.5~31.5	78	600	0.25	0.1	23	17		
1N6012B	33	5	31.35~34.65	88	700	0.25	0.1	25	15		
1N6013B	36	5	34.2~37.8	95	700	0.25	0.1	27	14		
1N6014B	39	2	37.05~40.95	130	800	0.25	0.1	30	13		
1N6015B	43	2	40.85~45.15	150	900	0.25	0.1	33	12		
1N6016B	47	2	44.65~49.35	170	1000	0.25	0.1	36	11		

¹⁾ Tolerance and voltage designation(Vz):

Tolerance designation – Device tolerance of ±5% is indicated by a “B” suffix.

²⁾ Maximum zener current ratings(I_{ZM}):

This data was calculated using nominal voltages. The maximum current handling capability on a worst case basis is limited by the actual zener voltage at the operation point and the power derating curve.

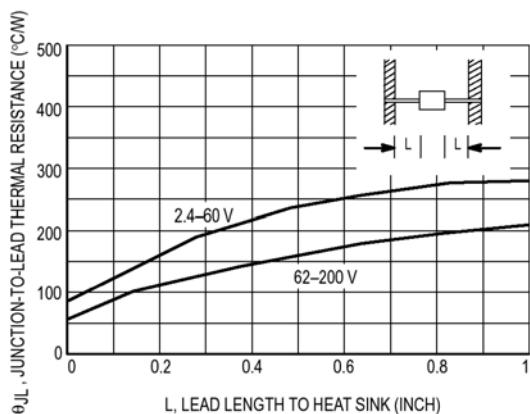
**Characteristics ($T_j=25^\circ\text{C}$ unless otherwise specified)**

Figure 1. Typical Thermal Resistance

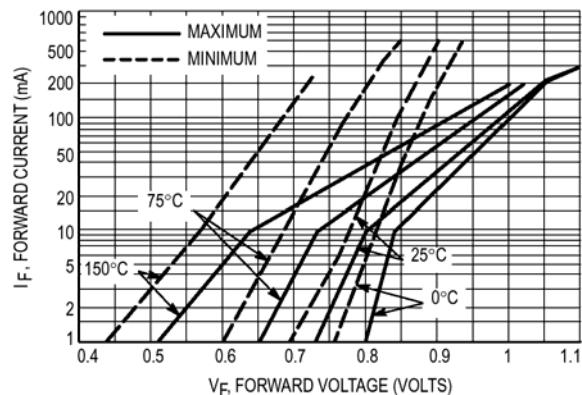


Figure 2. Typical Forward Characteristics

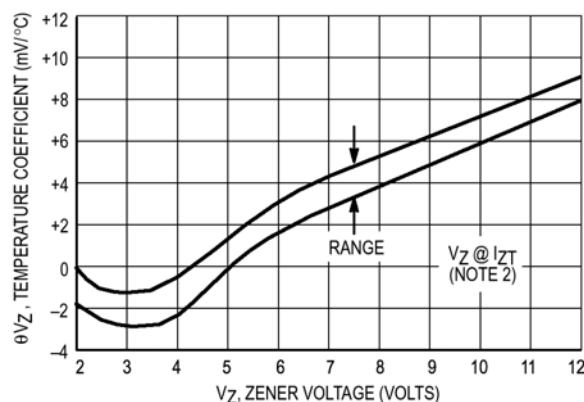
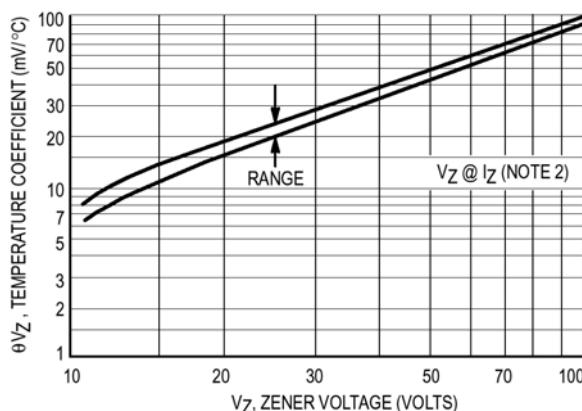


Figure 3. Temperature coefficients



(-55°C to +150°C temperature range; 90% of the units are in the ranges indicated.)

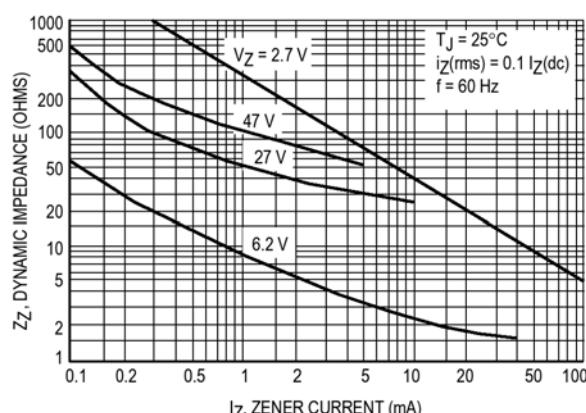


Figure 4. Effect of zener current on zener impedance

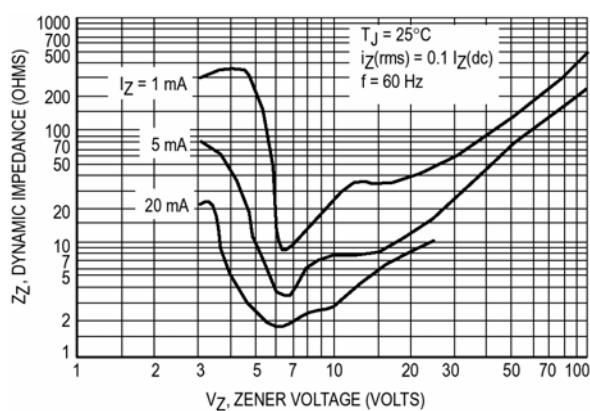


Figure 5. Effect of zener voltage on zener impedance

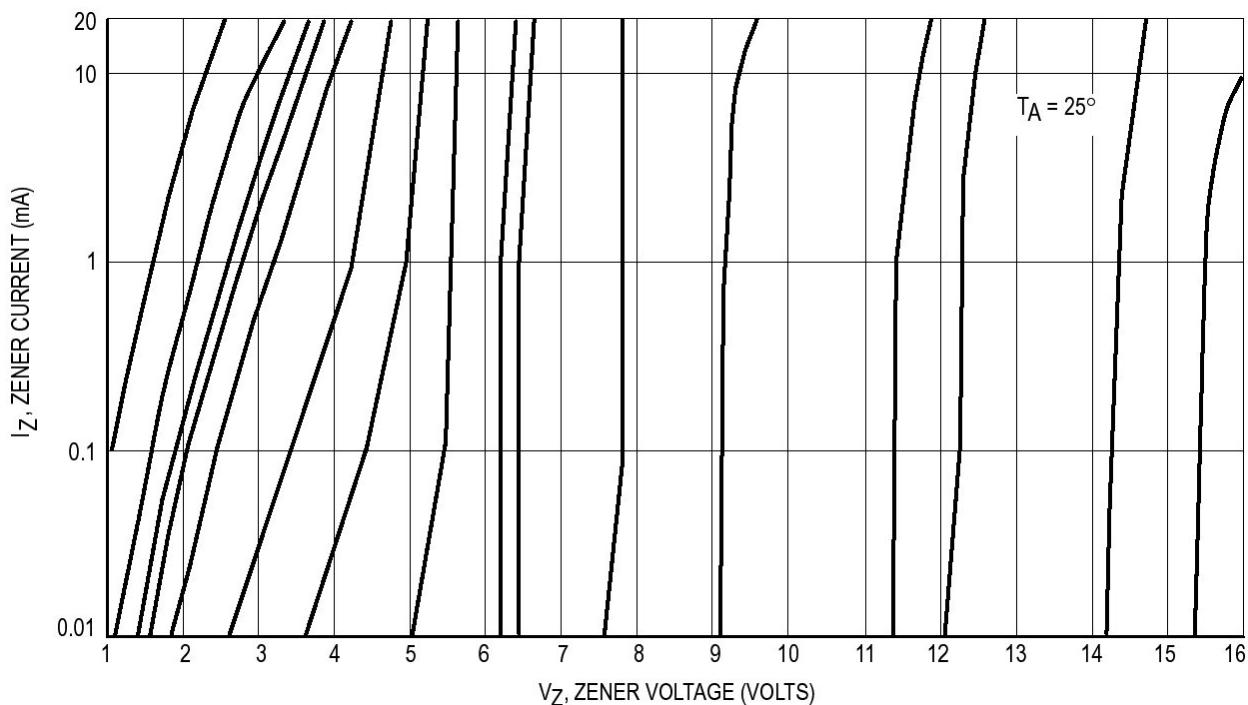


Figure 6. Zener Voltage versus Zener Current – $V_z=1$ thru 16 Volts

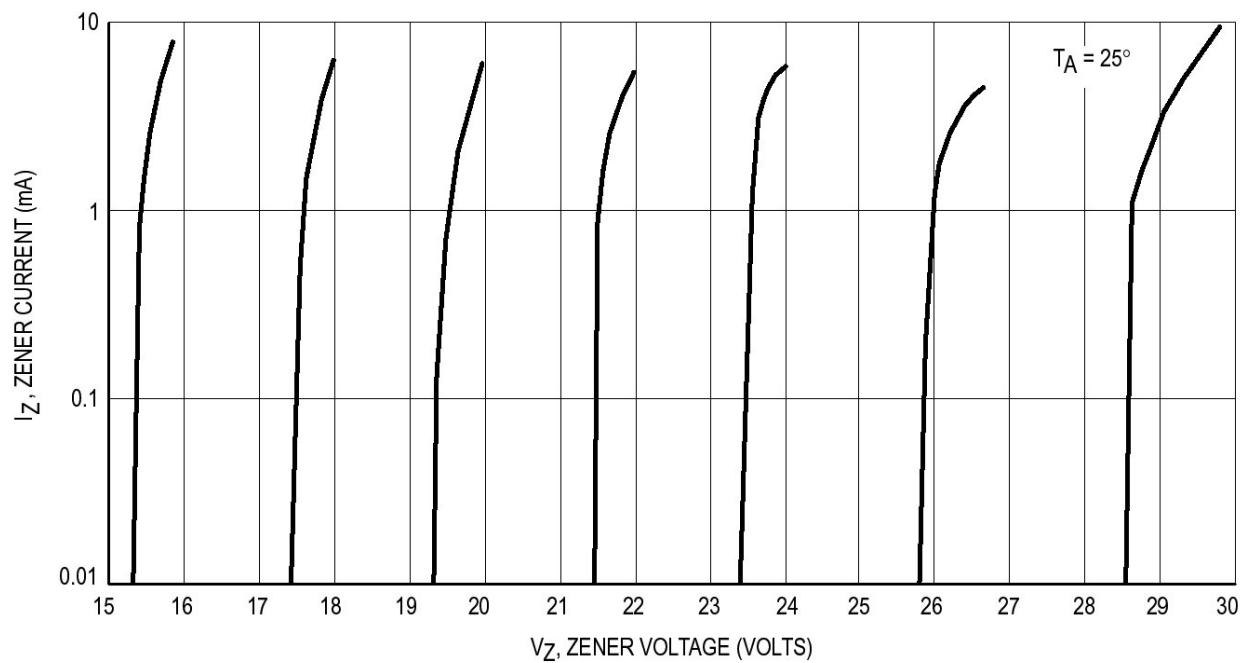


Figure 7. Zener Voltage versus Zener Current – $V_z=15$ thru 30 Volts

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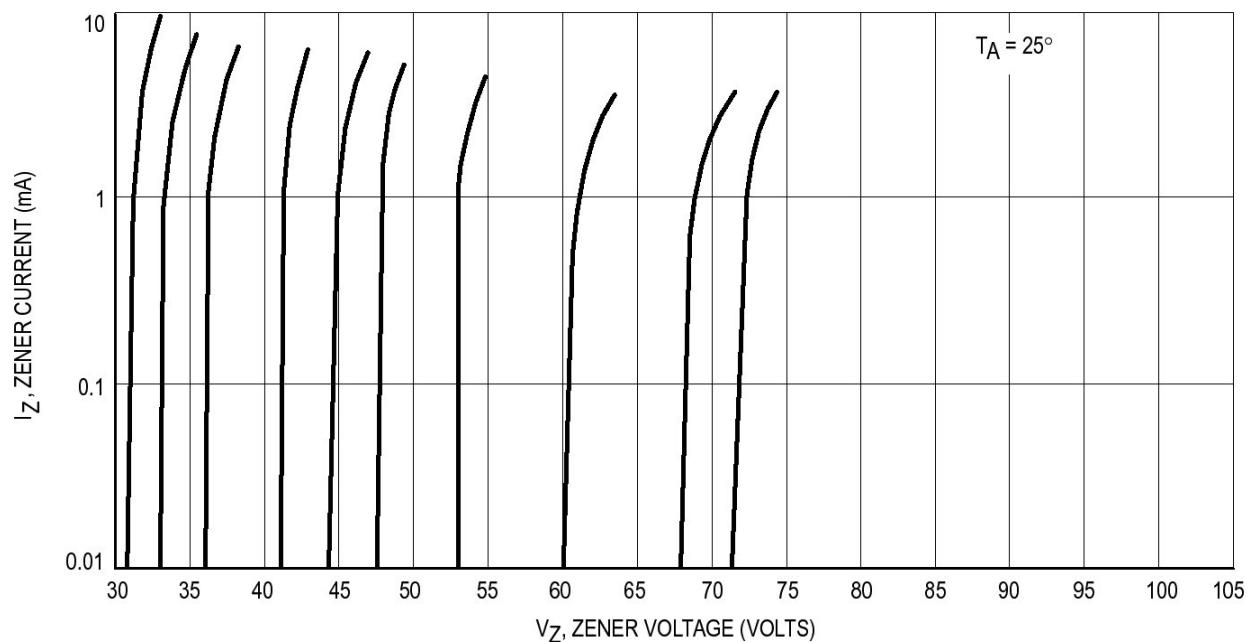
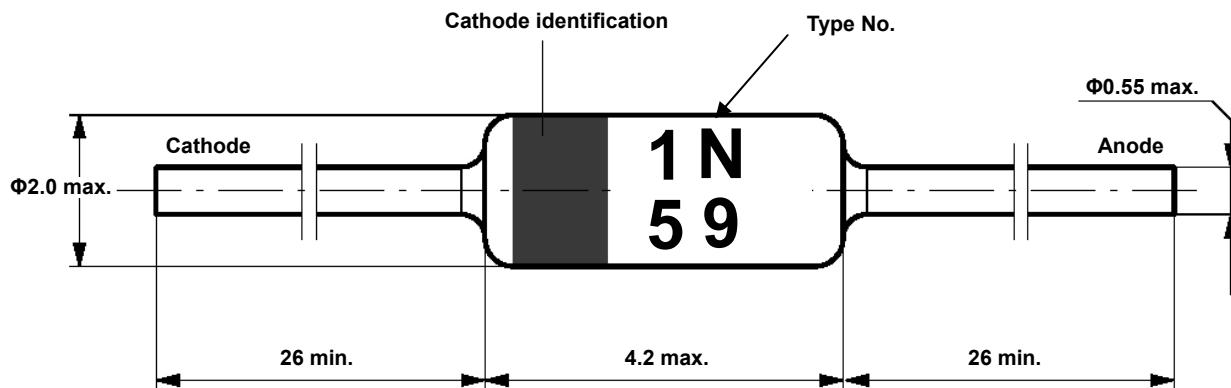


Figure 8. Zener Voltage versus Zener Current – $V_z=30$ thru 75 Volts

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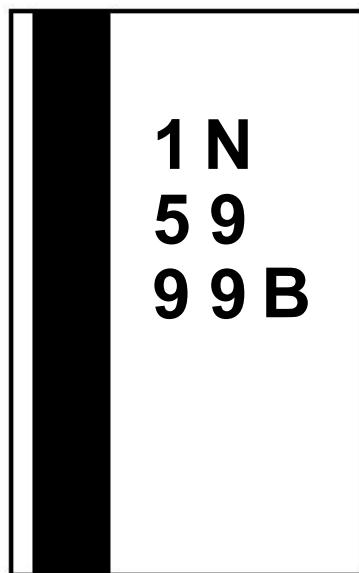


Dimensions in mm



Standard Glass Case
JEDEC DO-35

Marking



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